COMPLIANT

HALOGEN **FREE**





N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
30	0.0045 at V _{GS} = 10 V	20		
	0.0055 at V _{GS} = 4.5 V	17		

SO-8 D Top View

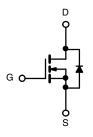
Ordering Information: Si4406DY-T1-E3 (Lead (Pb)-free) Si4406DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 **Available**
- TrenchFET® Power MOSFET
- Optimized for "Low Side" Synchronous **Rectifier Operation**
- 100 % R_g Tested

APPLICATIONS

- DC/DC Converters
- Synchronous Rectifiers



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	30		V
Gate-Source Voltage		V_{GS}	± 20		
Continuous Drain Current /T 150 °C\a	T _A = 25 °C	- I _D	20	13	Α
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		15	10	
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	60		Α .
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.3	
Marrian Danier Disairation	T _A = 25 °C	- P _D	3.5	1.6	W
Maximum Power Dissipation ^a	T _A = 70 °C		2.2	1	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manipulation to Application	t ≤ 10 s	- R _{thJA}	29	35	°C/W	
Maximum Junction-to-Ambient ^a	Steady State		67	80		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	13	16		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

Vishay Siliconix



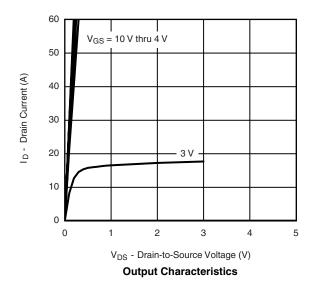
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0	1.95	3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zoro Coto Voltogo Droin Current	I _{DSS} -	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1		
Zero Gate Voltage Drain Current		V _{DS} = 30 V, V _{GS} = 0 V, T _J = 55 °C			5	- μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α	
D : 0	Ь	V _{GS} = 10 V, I _D = 20 A		0.0035	0.0045	0	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 19 \text{ A}$		0.0043	0.0055	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		95		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.72	1.1	V	
Dynamic ^b							
Total Gate Charge	Q_g			34	50		
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		15		nC	
Gate-Drain Charge	Q_{gd}			10			
Gate Resistance	R_g		0.5	1.3	2.2	Ω	
Turn-On Delay Time	t _{d(on)}			21	35		
Rise Time	t _r	$V_{DD} = 15 \text{ V}, R_{L} = 15 \Omega$		15	25	ns	
Turn-Off Delay Time	t _{d(off)}			100	150		
Fall Time	t _f			30	45	110	
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 2.9 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}$		50	80		

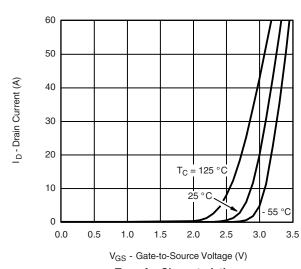
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





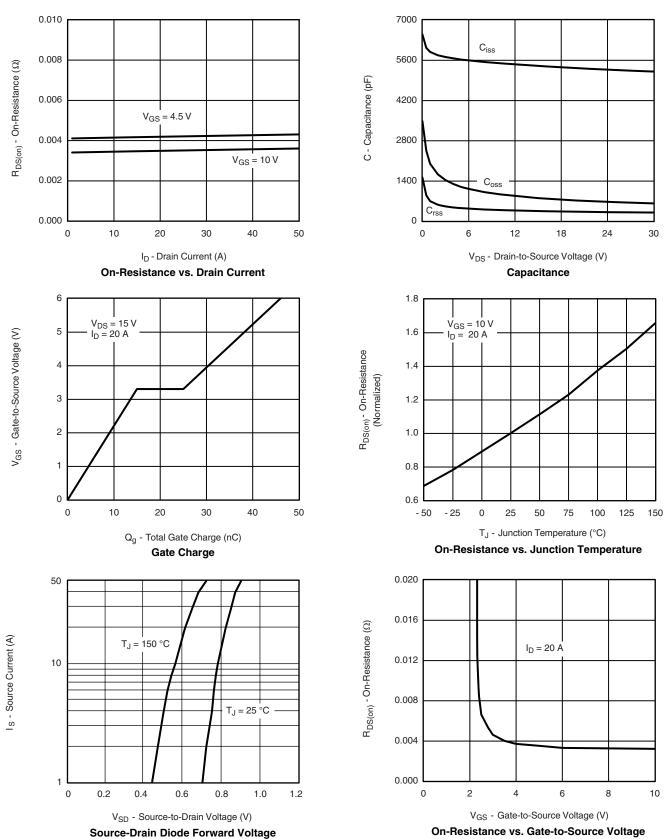
Transfer Characteristics







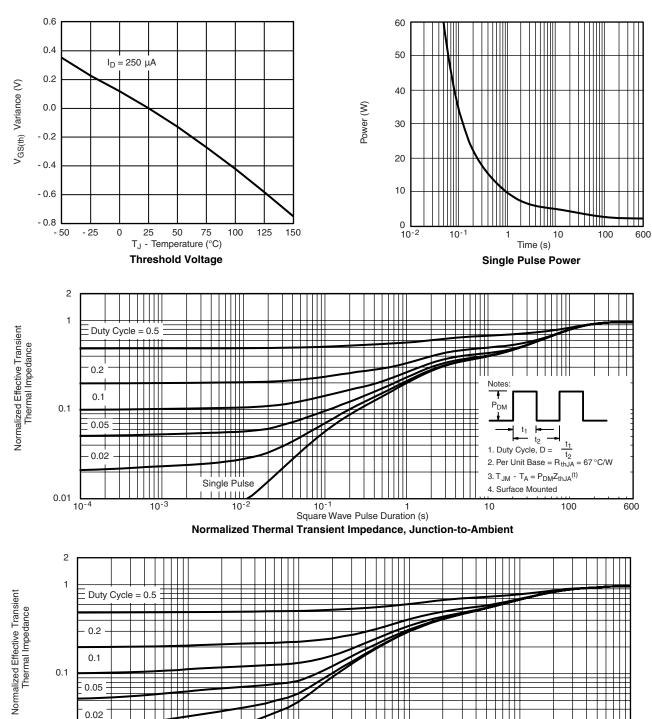
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Square Wave Pulse Duration (s)

Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71824.

Single Pulse

10⁻³



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